

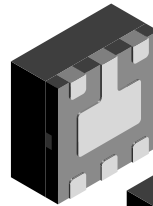
5-Line ESD-Protection Diode Array in LLP75-6A

Features

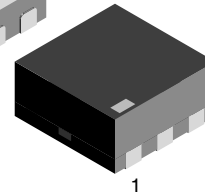
- Ultra compact LLP75-6A package
- 5-line ESD-protection
- Low leakage current $I_R < 0.1 \mu A$
- Low load capacitance of typ. 43 pF at $V_R = 0 V$
- ESD-immunity acc. IEC 61000-4-2 $\pm 30 kV$ contact discharge
 $\pm 30 kV$ air discharge
- Working voltage range $V_{RWM} = 5 V$
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



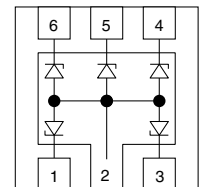
RoHS
COMPLIANT
GREEN
(5-2008)*



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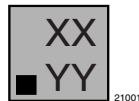


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Marking (example only)



21001

Dot = Pin 1 marking

XX = Date code

YY = Type code (see table below)

Ordering Information

Device name	Ordering code	Taped units per reel (8 mm tape on 7" reel)	Minimum order quantity
GMF05LC-HS3	GMF05LC-HS3-GS08	3000	15000

Package Data

Device name	Package name	Type code	Weight	Molding compound flammability rating	Moisture sensitivity level	Soldering conditions
GMF05LC-HS3	LLP75-6A	F6	5.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

Absolute Maximum Ratings

Rating	Test condition		Symbol	Value	Unit
Peak pulse current	BiAs-mode: each input (pin 1; 3 - pin 6) to ground (pin 2); acc. IEC 61000-4-5; t _p = 8/20 μs; single shot		I _{PPM}	5	A
Peak pulse power	BiAs-mode: each input (pin 1; 3 - pin 6) to ground (pin 2); acc. IEC 61000-4-5; t _p = 8/20 μs; single shot		P _{PP}	70	W
ESD-immunity	acc. IEC61000-4-2; 10 pulses BiAs-mode: each input (pin 1; 3 - pin 6) to ground (pin 2)	contact discharge	V _{ESD}	± 30	kV
		air discharge	V _{ESD}	± 30	kV
Operating temperature	Junction temperature		T _J	- 55 to + 125	°C
Storage temperature			T _{STG}	- 55 to + 150	°C

* Please see document "Vishay Green and Halogen-Free Definitions (5-2008)" <http://www.vishay.com/doc?99902>

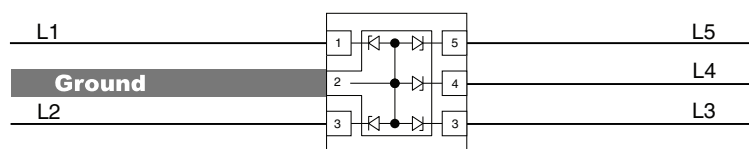
BiAs-Mode (5-line Bidirectional Asymmetrical protection mode)

With the **GMF05LC-HS3** up to 5 signal- or data-lines (L1 - L5) can be protected against voltage transients. With pin 2 connected to ground and pin 1; 3 up to pin 6 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified **Maximum Reverse Working Voltage (V_{RWM})** the protection diode between data line and ground offer a high isolation to the ground line. The protection device behaves like an open switch.

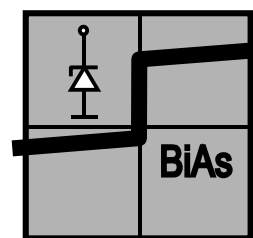
As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The **Clamping Voltage (V_C)** is defined by the **Breakthrough Voltage (V_{BR})** level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low **Forward Voltage (V_F)** clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the **GMF05LC-HS3** clamping behaviour is **Bidirectional** and **Asymmetrical (BiAs)**.



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Electrical Characteristics

Ratings at 25 °C ambient temperature, unless otherwise specified

GMF05LC-HS3

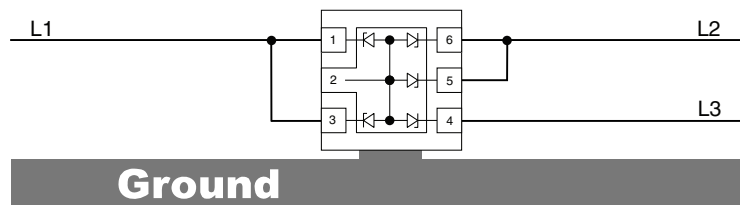
BiAs mode: each input (pin 1, 3, 4, 5, 6) to ground (pin 2)

Parameter	Test conditions/remarks	Symbol	Min.	Typ.	Max.	Unit
Protection paths	number of line which can be protected	N lines			5	lines
Reverse stand-off voltage	at $I_R = 1 \mu A$	V_{RWM}	5			V
Reverse current	at $V_R = V_{RWM} = 5 V$	I_R		0.01	0.1	μA
Reverse breakdown voltage	at $I_R = 1 mA$	V_{BR}	6		8	V
Reverse clamping voltage	at $I_{PP} = 1 A$; acc. IEC 61000-4-5	V_C		8	9.5	V
	at $I_{PP} = I_{PPM} = 5 A$; acc. IEC 61000-4-5	V_C		11.5	12.5	V
Forward clamping voltage	at $I_F = 1 A$; acc. IEC 61000-4-5	V_F		1.5	2	V
	at $I_{PP} = I_{PPM} = 5 A$; acc. IEC 61000-4-5	V_F		3.1	4	V
Line capacitance	at $V_R = 0 V$; $f = 1 MHz$	C_D		43	50	pF
	at $V_R = 2.5 V$; $f = 1 MHz$	C_D		25		pF

If a higher surge current or **Peak Pulse current (I_{PP})** is needed, some protection diodes in the **GMF05LC-HS3** can also be used in parallel in order to "multiply" the performance.

If two diodes are switched in parallel you get

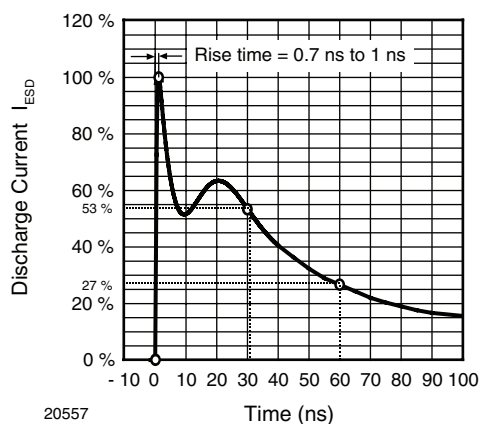
- double surge power = double peak pulse current ($2 \times I_{PPM}$)
- half of the line inductance = reduced clamping voltage
- half of the line resistance = reduced clamping voltage
- double line Capacitance ($2 \times C_D$)
- double **Reverse leakage current** ($2 \times I_R$)



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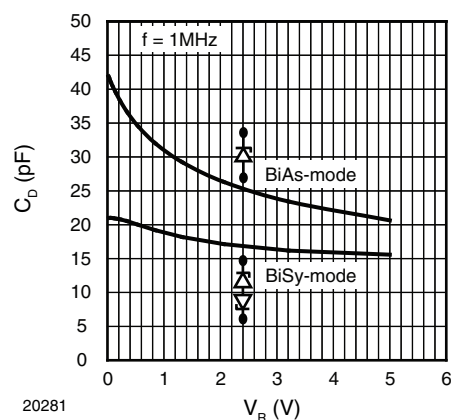
Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified



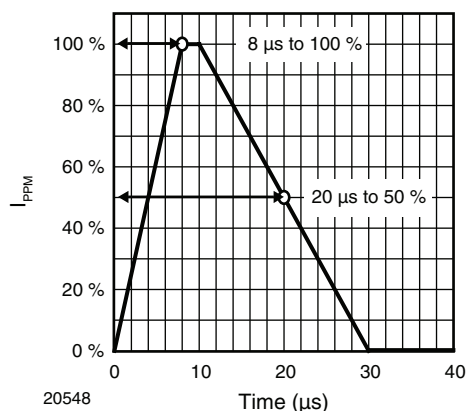
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Figure 1. ESD Discharge Current Wave Form
acc. IEC 61000-4-2 (330 Ω /150 pF)



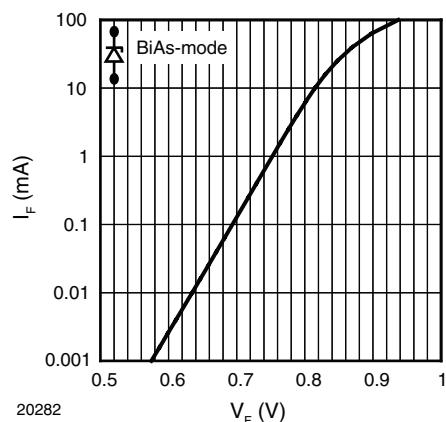
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Figure 3. Typical Capacitance C_D vs. Reverse Voltage V_R



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Figure 2. 8/20 μ s Peak Pulse Current Wave Form
acc. IEC 61000-4-5



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Figure 4. Typical Forward Current I_F vs. Forward Voltage V_F

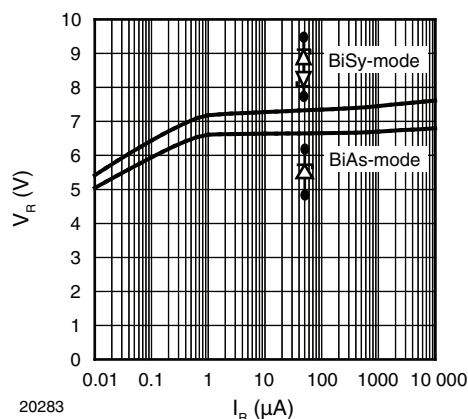


Figure 5. Typical Reverse Voltage V_R vs. Reverse Current I_R

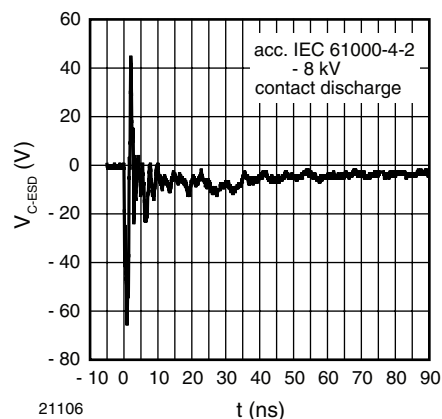


Figure 8. Typical Clamping performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

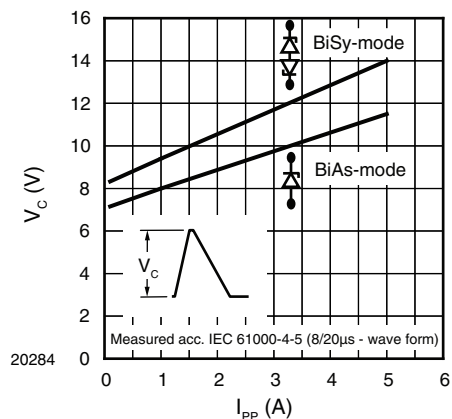


Figure 6. Typical Peak Clamping Voltage V_C vs. Peak Pulse Current I_{PP}

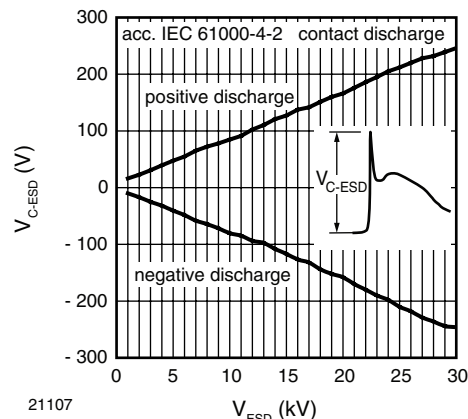


Figure 9. Typical Peak Clamping Voltage at ESD Contact Discharge (acc. IEC 61000-4-2)

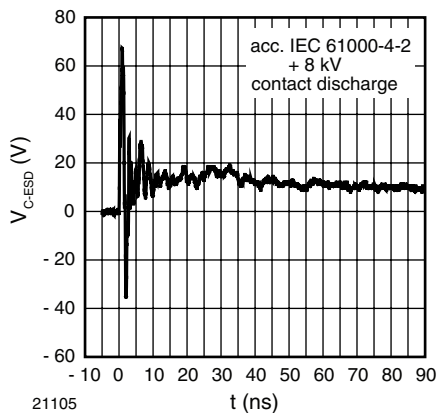
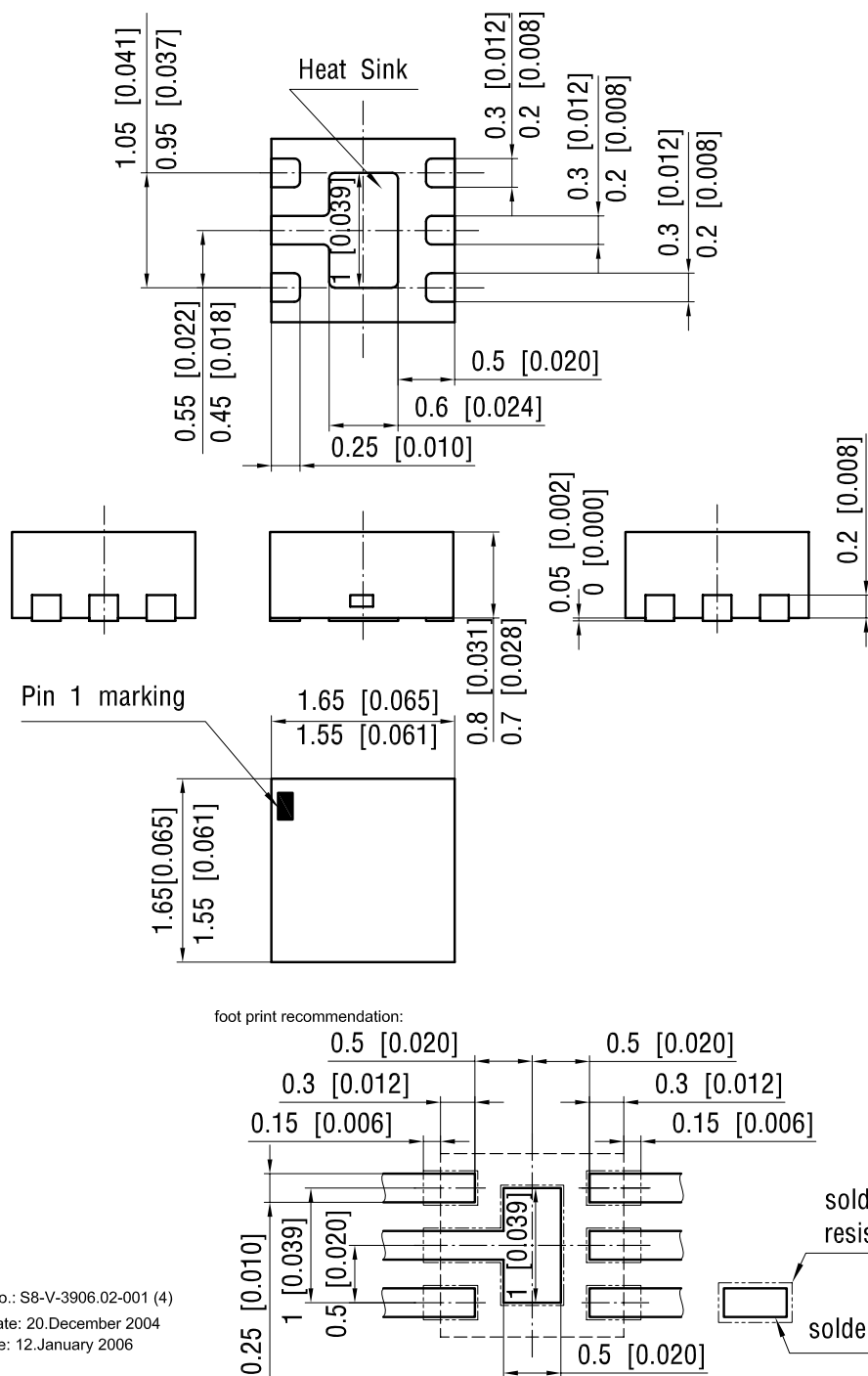


Figure 7. Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

Package Dimensions in millimeters (inches): LLP75-6A



Document no.: S8-V-3906.02-001 (4)
 Created - Date: 20.December 2004
 Rev. b - Date: 12.January 2006
 18058

Ozone Depleting Substances Policy Statement

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1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
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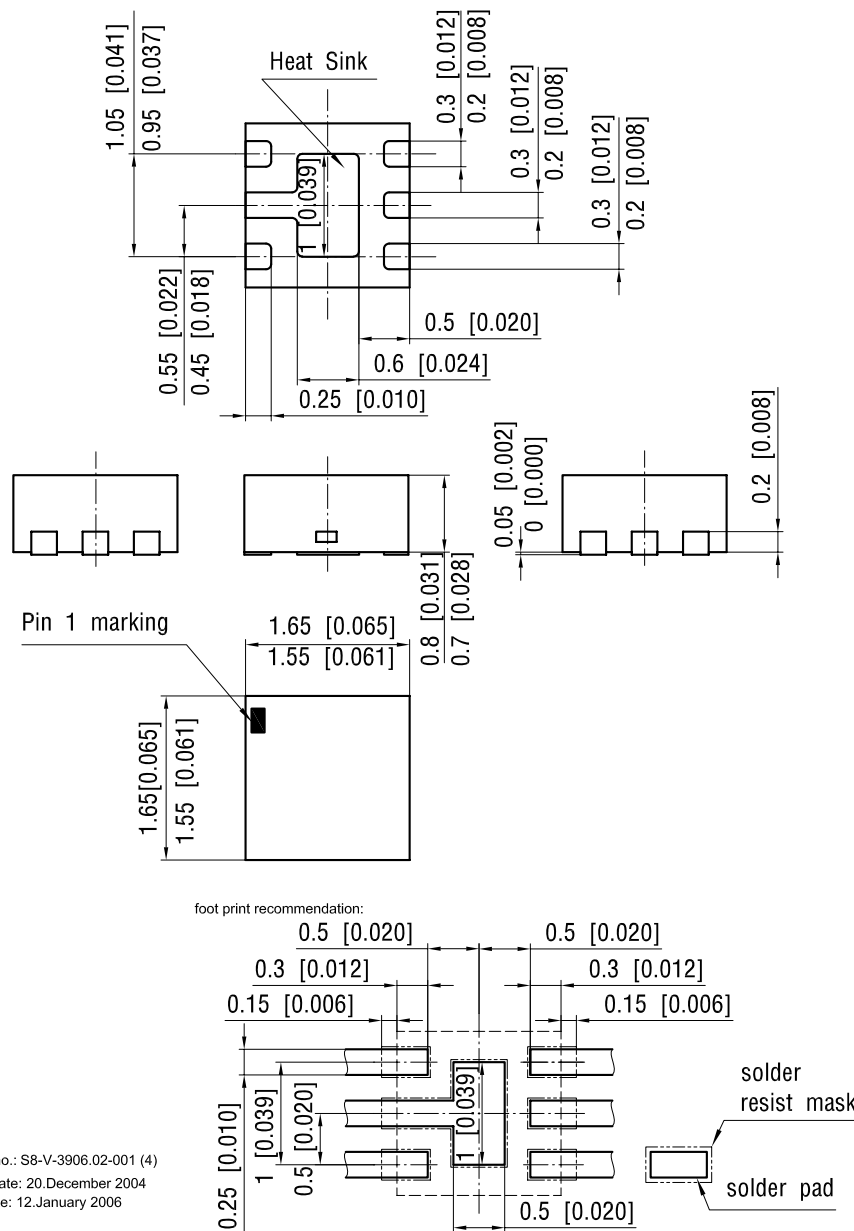
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LLP75-6A

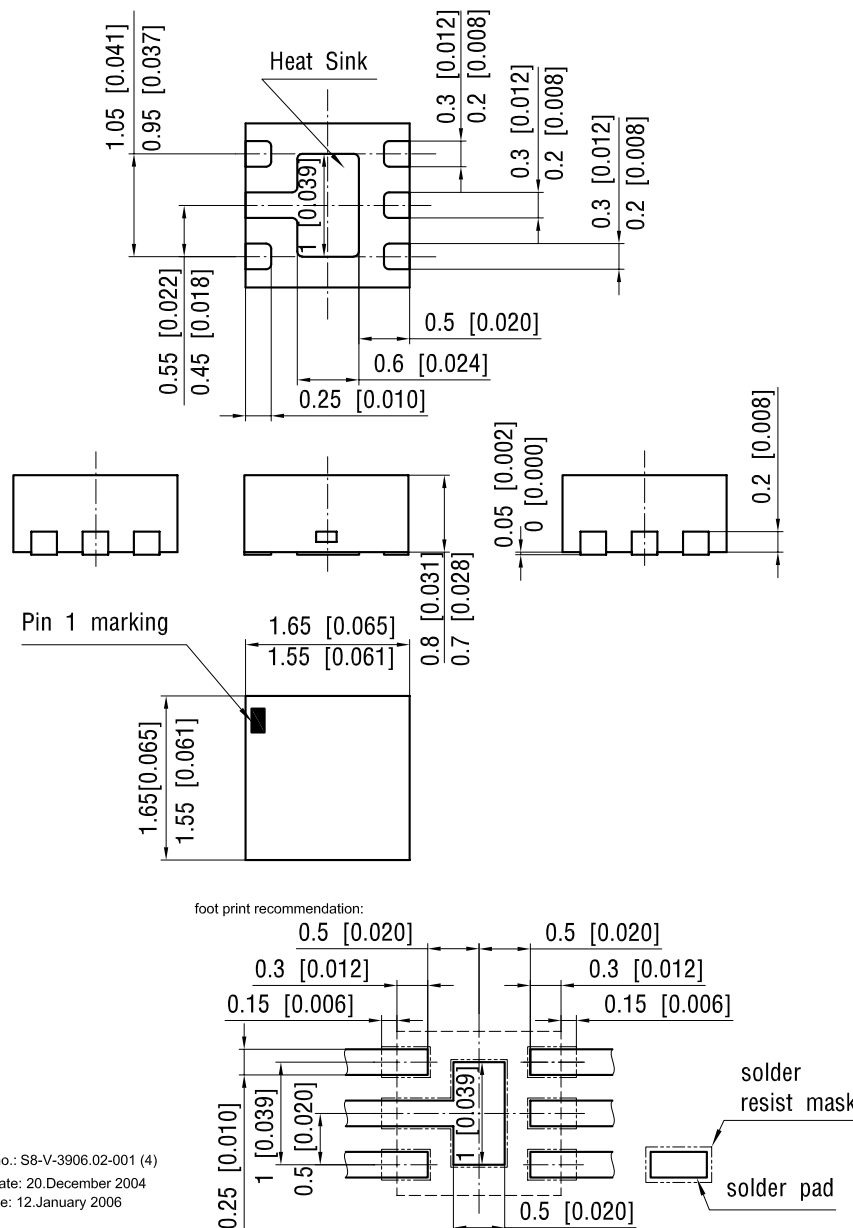
Package Dimensions in mm (Inches)



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